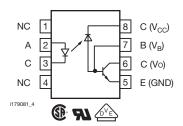




High Speed Optocoupler, 1 MBd, Photodiode with Transistor Output





DESCRIPTION

The 6N135 and 6N136 are optocouplers with a GaAlAs infrared emitting diode, optically coupled with an integrated photo detector which consists of a photo diode and a high-speed transistor in a DIP-8 plastic package.

Signals can be transmitted between two electrically separated circuits up to frequencies of 2 MHz. The potential difference between the circuits to be coupled should not exceed the maximum permissible reference voltages.

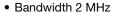
FEATURES

Isolation test voltages: 5300 V_{RMS}



• High bit rates: 1 Mbit/s

• High common-mode interference immunity



Open-collector output

• External base wiring possible

 Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC





RoHS

AGENCY APPROVALS

- UL1577, file no. E52744 system code H double protection
- DIN EN 60747-5-2 (VDE0884)/DIN EN 60747-5-5 (pending), available with option 1
- CSA 93751

ORDERING INFORMATION				
6 N 1 3 # PART NUMBER	- X 0 # # PACKAGE OPTION	TAPE AND REEL Option 7 Option 9 > 0.7 mm		
AGENCY CERTIFIED/PACKAGE	CTR	7 00 000		
UL, CSA	≥7	≥ 19		
DIP-8	6N135 6N136			
DIP-8, 400 mil, option 6	-	6N136-X006		
SMD-8, option 7	6N135-X007T ⁽¹⁾	6N136-X007T ⁽¹⁾		
SMD-8, option 9	-	6N136-X009T ⁽¹⁾		
VDE, UL, CSA	≥7	≥ 19		
DIP-8	-	6N136-X001		
DIP-8, 400 mil, option 6		6N136-X016		
SMD-8, option 7	6N135-X017T ⁽¹⁾	6N136-X017T		
SMD-8, option 9	-	6N136-X019T		

Note

⁽¹⁾ Also available in tubes; do not add T to end

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)										
PARAMETER TEST CONDITION SYMBOL VALUE UNIT										
INPUT										
Reverse voltage		V_R	5	V						
Forward current		I _F	25	mA						
Peak forward current	t = 1 ms, duty cycle 50 %	I _{FSM}	50	mA						
Maximum surge forward current	t ≤ 1 µs, 300 pulses/s		1	Α						
Thermal resistance		R _{th}	700	K/W						
Power dissipation	T _{amb} = 70 °C	P _{diss}	45	mW						

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
OUTPUT							
Supply voltage		Vs	- 0.5 to 15	V			
Output voltage		Vo	- 0.5 to 15	V			
Emitter base voltage		V _{EBO}	5	V			
Output current		I _O	8	mA			
Maximum output current			16	mA			
Base current		I _B	5	mA			
Thermal resistance			300	K/W			
Power dissipation	T _{amb} = 70 °C	P _{diss}	100	mW			
COUPLER			<u> </u>				
Isolation test voltage between emitter and detector	t = 1 s	V_{ISO}	5300	V_{RMS}			
Pollution degree (DIN VDE 0109)			2				
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω			
Isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω			
Storage temperature range		T _{stg}	- 55 to + 125	°C			
Ambient temperature range		T _{amb}	- 55 to + 100	°C			
Soldering temperature (1)	max. ≤ 10 s, dip soldering ≥ 0.5 mm from case bottom	T _{sld}	260	°C			

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT									
Forward voltage	I _F = 16 mA		V_{F}		1.33	1.9	V		
Breakdown voltage	I _R = 10 μA		V_{BR}	5			V		
Reverse current	V _R = 5 V		I _R		0.5	10	μA		
Capacitance	$V_R = 0 V, f = 1 MHz$		Co		30		pF		
Temperature coefficient, forward voltage	I _F = 16 mA		$\Delta V_F/\Delta T_A$		- 1.7		mV/°C		
OUTPUT									
Logic low supply current	$I_F = 16 \text{ mA}, V_O = \text{open},$ $V_{CC} = 15 \text{ V}$		I _{CCL}		150		μΑ		
Logic high supply current	$I_F = 0$ mA, $V_O = $ open, $V_{CC} = 15$ V		I _{CCH}		0.01	1	μΑ		
Output valtage output low	$I_F = 16 \text{ mA}, I_O = 1.1 \text{ mA},$ $V_{CC} = 4.5 \text{ V}$	6N135	V _{OL}		0.1	0.4	V		
Output voltage, output low	I_F = 16 mA, I_O = 2.4 mA, V_{CC} = 4.5 V	6N136	V _{OL}		0.1	0.4	V		
Output ourront output high	$I_F = 0 \text{ mA}, V_O = V_{CC} = 5.5 \text{ V}$		I _{OH}		3	500	nA		
Output current, output high	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}$		I _{OH}		0.01	1	μΑ		
COUPLER									
Capacitance (input to output)	f = 1 MHz		C _{IO}		0.6		pF		

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.



CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER TEST CONDITION PART SYMBOL MIN. TYP. MAX. UNIT								
Current transfer ratio	$I_F = 16$ mA, $V_O = 0.4$ V, $V_{CC} = 4.5$ V	6N135	CTR	7	16		%	
		6N136	CTR	19	35		%	
	$I_F = 16 \text{ mA}, V_O = 0.5 \text{ V},$	6N135	CTR	5			%	
	$V_{CC} = 4.5 \text{ V}$	6N136	CTR	15			%	

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TER TEST CONDITION PART SYMBOL MIN. TYP. MAX. UNIT							
High to low	$I_F = 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 4.1 \text{ k}\Omega$	6N135	t _{PHL}		0.3	1.5	μs	
	$I_F = 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1.9 \text{ k}\Omega$	6N136	t _{PHL}		0.2	0.8	μs	
Lourto high	$I_F = 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 4.1 \text{ k}\Omega$	6N135	t _{PLH}		0.3	1.5	μs	
Low to high	$I_F = 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1.9 \text{ k}\Omega$	6N136	t _{PLH}		0.2	0.8	μs	

COMMON MODE TRANSIENT IMMUNITY (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	AMETER TEST CONDITION PART SYMBOL MIN. TYP. MAX. UNIT							
High	$I_F = 0 \text{ mA}, V_{CM} = 10 V_{P-P}, V_{CC} = 5 V, R_L = 4.1 k\Omega$	6N135	CM _H		1000		V/µs	
	$I_F = 0 \text{ mA}, V_{CM} = 10 V_{P-P}, V_{CC} = 5 V, R_L = 1.9 k\Omega$	6N136	CM _H		1000		V/µs	
Low	$I_F = 16 \text{ mA}, V_{CM} = 10 V_{P-P}, V_{CC} = 5 V, R_L = 4.1 \text{ k}\Omega$	6N135	CM _L		1000		V/µs	
	$I_F = 16 \text{ mA}, V_{CM} = 10 V_{P-P}, V_{CC} = 5 V, R_L = 1.9 \text{ k}\Omega$	6N136	CM _L		1000		V/µs	

SAFETY AND INSULATION RATINGS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Climatic classification (according to IEC 68 part 1)				55/100/21				
Comparative tracking index		CTI	175		399			
V _{IOTM}			8000			V		
V _{IORM}			890			V		
P _{SO}					500	mW		
I _{SI}					300	mA		
T _{SI}					175	°C		
Creepage distance	Standard DIP-8		7			mm		
Clearance distance	Standard DIP-8		7			mm		
Creepage distance	400 mil DIP-8		8			mm		
Clearance distance	400 mil DIP-8		8			mm		

Note

According to DIN EN 60747-5-2 (VDE 0884), this optocoupler is suitable for "safe electrical insulation" only within the safety ratings.
 Compliance with the safety ratings shall be ensured by means of protective circuits.



TYPICLA CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

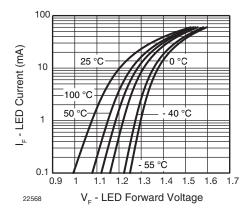


Fig. 1 - LED Forward Current vs. Forward Voltage

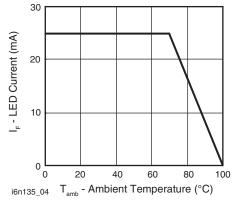


Fig. 2 - Permissible Forward LED Current vs. Temperature

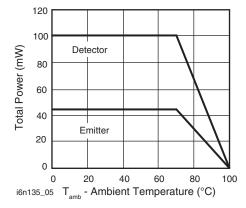


Fig. 3 - Permissible Power Dissipation vs. Temperature

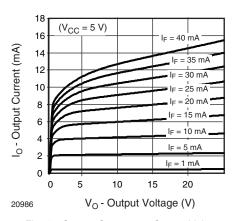


Fig. 4 - Output Current vs. Output Voltage

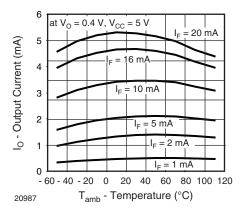


Fig. 5 - Output Current vs. Temperature

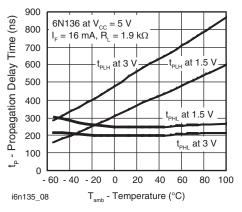


Fig. 6 - Propagation Delay vs. Ambient Temperature



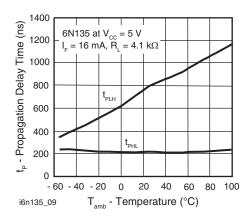


Fig. 7 - Propagation Delay vs. Ambient Temperature

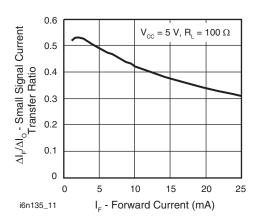


Fig. 9 - Small Signal Current Transfer Ratio vs. Quiescent Input Current

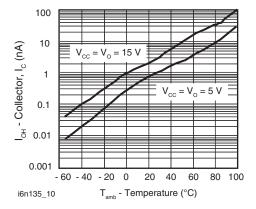


Fig. 8 - Logic High Output Current vs. Temperature

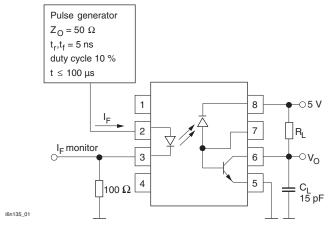
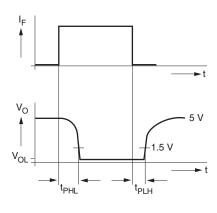


Fig. 10 - Switching Times





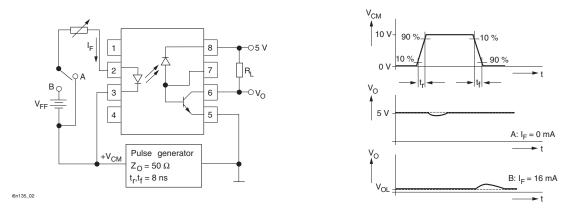
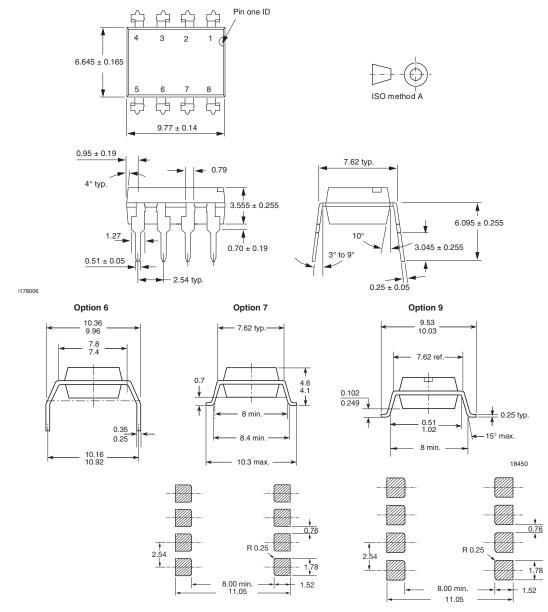


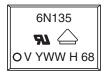
Fig. 11 - Common-Mode Interference Immunity

PACKAGE DIMENSIONS in millimeters





PACKAGE MARKING



Notes

- Only options 1, and 7 are reflected in the package marking.
- The VDE logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.

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